SCES066G - JUNE 1996 - REVISED APRIL 2002

<ul> <li>State-of-the-Art Advanced BiCMOS Technology (ABT) Widebus<sup>™</sup> Design for 2.5-V and 3.3-V Operation and Low Static-Power Dissipation</li> </ul>	SN54ALVTH16245 WD PACKAGE SN74ALVTH16245 DGG, DGV, OR DL PACKAGE (TOP VIEW)
<ul> <li>Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V<sub>CC</sub>)</li> </ul>	1DIR [] 1 48 [] 1 <del>OE</del> 1B1 [] 2 47 [] 1A1 1B2 [] 3 46 [] 1A2 GND [] 4 45 [] GND
<ul> <li>Typical V<sub>OLP</sub> (Output Ground Bounce)</li> <li>&lt;0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C</li> </ul>	1B3 [ 5 44 ] 1A3 1B4 [ 6 43 ] 1A4
<ul> <li>High Drive (-32/64 mA at 3.3-V V<sub>CC</sub>)</li> <li>I<sub>off</sub> and Power-Up 3-State Support Hot Insertion</li> </ul>	V <sub>CC</sub> [] 7 42 ]] V <sub>CC</sub> 1B5 [] 8 41 ]] 1A5 1B6 [] 9 40 ]] 1A6
<ul> <li>Use Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating</li> </ul>	GND [] 10 39 ]] GND 1B7 [] 11 38 ]] 1A7 1B8 [] 12 37 ]] 1A8
<ul> <li>Flow-Through Architecture Facilitates Printed Circuit Board Layout</li> </ul>	2B1 0 13 36 0 2A1 2B2 0 14 35 0 2A2 GND 0 15 34 0 GND
<ul> <li>Distributed V<sub>CC</sub> and GND Pins Minimize High-Speed Switching Noise</li> </ul>	2B3 16 33 2A3 2B4 17 32 2A4
<ul> <li>Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II</li> </ul>	2B3 16 33 2A3 2B4 17 32 2A4 V <sub>CC</sub> 18 31 V <sub>CC</sub> 2B5 19 30 2A5 2B6 20 29 2A6 GND 21 28 GND
description	
The 'ALVTH16245 devices are 16-bit (dual-octal) noninverting 3-state transceivers designed for $2.5-V$ or $3.3-V$ V <sub>CC</sub> operation, but with the	2B7 [ 22 27 ] 2A7 2B8 [ 23 26 ] 2A8 2DIR [ 24 25 ] 2OE

2.5-V or 3.3-V V<sub>CC</sub> operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices can be used as two 8-bit transceivers or one 16-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable ( $\overline{OE}$ ) input can be used to disable the device so that the buses are effectively isolated.

These devices are fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V<sub>CC</sub> is between 0 and 1.2 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



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SCES066G – JUNE 1996 – REVISED APRIL 2002

#### SN74ALVTH16245 ... GQL PACKAGE (TOP VIEW) 1 2 3 4 5 6 000000 Α в 00000 000000 С 00000 D $\bigcirc \bigcirc$ $\bigcirc \bigcirc$ Е $\bigcirc \bigcirc$ $\bigcirc \bigcirc$ F G 000000 Н 000000 J κ

#### terminal assignments

	1	2	3	4	5	6
Α	1DIR	NC	NC	NC	NC	1 <mark>0E</mark>
в	1B2	1B1	GND	GND	1A1	1A2
С	1B4	1B3	VCC	V <sub>CC</sub>	1A3	1A4
D	1B6	1B5	GND	GND	1A5	1A6
Е	1B8	1B7			1A7	1A8
F	2B1	2B2			2A2	2A1
G	2B3	2B4	GND	GND	2A4	2A3
н	2B5	2B6	VCC	V <sub>CC</sub>	2A6	2A5
J	2B7	2B8	GND	GND	2A8	2A7
κ	2DIR	NC	NC	NC	NC	2 <mark>0E</mark>

NC - No internal connection

#### **ORDERING INFORMATION**

		UNDERING		1
TA	PACKA	GE†	ORDERABLE PART NUMBER	
–40°C to 85°C	SSOP – DL	Tape and reel	SN74ALVTH16245DLR	ALVTH16245
	TSSOP – DGG	Tape and reel	SN74ALVTH16245GR	ALVTH16245
-40 C 10 85 C	TVSOP – DGV	Tape and reel	SN74ALVTH16245VR	VT245
	VFBGA – GQL	Tape and reel	SN74ALVTH16245QR	
–55°C to 125°C	CFP – WD	Tube	SNJ54ALVTH16245WD	SNJ54ALVTH16245WD

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

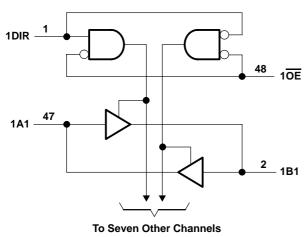
# FUNCTION TABLE (each 8-bit section)

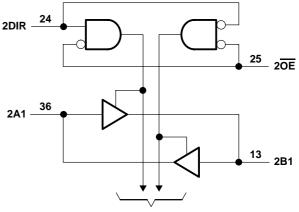
INP	UTS	OPERATION
OE	DIR	OFERATION
L	L	B data to A bus
L	н	A data to B bus
Н	Х	Isolation



SCES066G - JUNE 1996 - REVISED APRIL 2002

### logic diagram (positive logic)





**To Seven Other Channels** 

Pin numbers shown are for the DGG, DGV, DL, and WD packages.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub>		
Input voltage range, V <sub>I</sub> (see Note 1)		
Voltage range applied to any output in t		
Output current in the low state, IO: SNE	54ALVTH16245	
SN7	74ALVTH16245	128 mA
Output current in the high state, IO: SN	54ALVTH16245	
SN	74ALVTH16245	–64 mA
Input clamp current, IIK (VI < 0)		
Output clamp current, IOK (VO < 0)		
Package thermal impedance, 0JA (see	Note 2): DGG package	
	DGV package	58°C/W
-	DL package	63°C/W
		42°C/W
Storage temperature range, T <sub>stg</sub>		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



# SN54ALVTH16245, SN74ALVTH16245 2.5-V/3.3-V 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS SCES066G – JUNE 1996 – REVISED APRIL 2002

### recommended operating conditions, V<sub>CC</sub> = 2.5 V $\pm$ 0.2 V (see Note 3)

			SN54	ALVTH1	6245	SN74	ALVTH1	6245		
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
VCC	Supply voltage		2.3		2.7	2.3		2.7	V	
VIH	High-level input voltage		1.7		2	1.7			V	
VIL	Low-level input voltage			101	0.7			0.7	V	
VI	Input voltage		0	Vcc	5.5	0	VCC	5.5	V	
IOH	High-level output current			7	-6			-8	-8 mA	
1	Low-level output current			50	6			8	~ ^	
IOL	Low-level output current; current duty cycle $\leq$	50%; f ≥ 1 kHz	0.0	5	18			24	mA	
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled	Þ		10			10	ns/V	
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200			200			μs/V	
Т <sub>А</sub>	Operating free-air temperature		-55		125	-40		85	°C	

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### recommended operating conditions, V<sub>CC</sub> = 3.3 V $\pm$ 0.3 V (see Note 3)

			SN54	ALVTH1	6245	SN74ALVTH16245		UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage	36	3	2	3.6	3		3.6	V
VIH	High-level input voltage		2		2	2			V
VIL	Low-level input voltage			1	0.8			0.8	V
VI	Input voltage		0	Vcc	5.5	0	VCC	5.5	V
ЮН	High-level output current			7	-24			-32	mA
lai	Low-level output current			50	24			32	mA
IOL	Low-level output current; current duty cycle ≤ 5	i0%; f ≥ 1 kHz	0	5	48			64	IIIA
$\Delta t / \Delta v$	Input transition rise or fall rate	Outputs enabled	P		10			10	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200			200			μs/V
ТА	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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SCES066G - JUNE 1996 - REVISED APRIL 2002

	DAMETED	TEAT OF		SN54	ALVTH1	6245	SN74	ALVTH1	6245	UNUT	
PA	RAMETER	TEST CO	ONDITIONS	MIN	TYP†	MAX	MIN	түр†	MAX	UNIT	
VIK		V <sub>CC</sub> = 2.3 V,	lj = -18 mA			-1.2			-1.2	V	
		V <sub>CC</sub> = 2.3 V to 2.7 V,	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> -0	.2		V <sub>CC</sub> -0	.2			
Vон		V <sub>CC</sub> = 2.3 V	$I_{OH} = -6 \text{ mA}$							V	
		VCC = 2.3 V	I <sub>OH</sub> = -8 mA				1.8				
		$V_{CC}$ = 2.3 V to 2.7 V,	I <sub>OL</sub> = 100 μA			0.2			0.2		
			I <sub>OL</sub> = 6 mA			0.4					
VOL		V <sub>CC</sub> = 2.3 V	I <sub>OL</sub> = 8 mA					0.4	V		
		VCC - 2.3 V	I <sub>OL</sub> = 18 mA			0.5					
			I <sub>OL</sub> = 24 mA	6		0.5					
	Control inputs	V <sub>CC</sub> = 2.7 V,	$V_I = V_{CC}$ or GND			±1			±1		
A or B ports	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	VI = 5.5 V		35	10			10			
		V <sub>CC</sub> = 2.7 V	V <sub>I</sub> = 5.5 V		20	20			20	μA	
	A or B ports		$V_I = V_{CC}$			1			1	1	
			V <sub>I</sub> = 0	40		-5			-5		
l <sub>off</sub>		V <sub>CC</sub> = 0,	$V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5 V_{O}$	2	6				±100	μA	
I <sub>BHL</sub> ‡		V <sub>CC</sub> = 2.3 V,	VI = 0.7 V		115			115		μA	
IBHH§		V <sub>CC</sub> = 2.3 V,	Vj = 1.7 V	01-	-10			-10		μA	
IBHLO	¶	V <sub>CC</sub> = 2.7 V,	VI = 0 to VCC	300			300			μA	
Івнно	,#	V <sub>CC</sub> = 2.7 V,	$V_I = 0$ to $V_{CC}$	-300			-300			μΑ	
IEX		V <sub>CC</sub> = 2.3 V,	V <sub>O</sub> = 5.5 V			125			125	μA	
IOZ(PL	J/PD) <sup>☆</sup>	$V_{CC} \le 1.2 \text{ V}, V_O = 0.5 \text{ V}$ V <sub>I</sub> = GND or V <sub>CC</sub> , OE =	to V <sub>CC</sub> , don't care			±100			±100	μA	
		$V_{CC} = 2.7 V,$	Outputs high	0.04		0.1		0.04	0.1		
ICC		$I_{O} = 0,$	Outputs low		2.3	4.5		2.3	4.5	mA	
		$V_{I} = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V <sub>CC</sub> = 2.5 V,	VI = 2.5 V or 0		3.5			3.5		pF	
Cio		V <sub>CC</sub> = 2.5 V,	V <sub>O</sub> = 2.5 V or 0		8			8		pF	

# electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 2.5 V $\pm$ 0.2 V (unless otherwise noted)

<sup>†</sup> All typical values are at V<sub>CC</sub> = 2.5 V, T<sub>A</sub> = 25°C.

<sup>‡</sup> The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>IN</sub> to GND and then raising it to V<sub>IL</sub> max.

§ The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to V<sub>CC</sub> and then lowering it to VIH min.

 $\P$  An external driver must source at least  $I_{BHLO}$  to switch this node from low to high.

# An external driver must sink at least IBHHO to switch this node from high to low.

II Current into an output in the high state when  $V_O > V_{CC}$ 

\*High-impedance state during power up or power down



### SN54ALVTH16245, SN74ALVTH16245 2.5-V/3.3-V 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS SCES066G – JUNE 1996 – REVISED APRIL 2002

electrical characteristics over recommended operating free-air temperature range,  $V_{CC}$  = 3.3 V  $\pm$  0.3 V (unless otherwise noted)

	DAMETED	TEOT	CONDITIONS	SN54	ALVTH1	6245	SN74	ALVTH1	6245	UNIT	
PA	ARAMETER	IESIC	CONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT	
VIK		V <sub>CC</sub> = 3 V,	lj = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 3 V \text{ to } 3.6 V,$	I <sub>OH</sub> = −100 μA	V <sub>CC</sub> -0	.2		V <sub>CC</sub> -0	2			
VOH		V <sub>CC</sub> = 3 V	I <sub>OH</sub> = -24 mA	2						V	
		vCC = 2 v	I <sub>OH</sub> = -32 mA				2				
		V <sub>CC</sub> = 3 V to 3.6 V,	I <sub>OL</sub> = 100 μA			0.2			0.2		
			I <sub>OL</sub> = 16 mA						0.4		
V <sub>OL</sub>			I <sub>OL</sub> = 24 mA			0.5				v	
		$V_{CC} = 3 V$	I <sub>OL</sub> = 32 mA						0.5	v	
			I <sub>OL</sub> = 48 mA			0.55					
			I <sub>OL</sub> = 64 mA			2			0.55		
	Control inputs	V <sub>CC</sub> = 3.6 V,	$V_I = V_{CC}$ or GND			±1			±1		
II A or B ports	V <sub>CC</sub> = 0 or 3.6 V,	VI = 5.5 V		24	10			10			
			VI = 5.5 V		1.3	20			20	μA	
	A or B ports	V <sub>CC</sub> = 3.6 V	$V_I = V_{CC}$		Sa "	1			1		
		V <sub>I</sub> = 0	1 3	D.a.	<b>C-</b> 5			-5			
loff		$V_{CC} = 0,$	V <sub>I</sub> or V <sub>O</sub> = 0 to 4.5 V	うび	2				±100	μA	
I <sub>BHL</sub> ‡		V <sub>CC</sub> = 3 V,	VI = 0.8 V	75			75			μA	
IBHH§		V <sub>CC</sub> = 3 V,	V <sub>1</sub> = 2 V	-75			-75			μΑ	
IBHLO		V <sub>CC</sub> = 3.6 V,	$V_{I} = 0$ to $V_{CC}$	500			500			μA	
Івннс	) <sup>#</sup>	V <sub>CC</sub> = 3.6 V,	$V_{I} = 0$ to $V_{CC}$	-500			-500			μA	
I <sub>EX</sub>		V <sub>CC</sub> = 3 V,	V <sub>O</sub> = 5.5 V			125			125	μA	
I <sub>OZ(Pl</sub>	J/PD) <sup>☆</sup>	$V_{CC} \le 1.2 \text{ V}, V_O = \frac{0.5}{0.5}$ V <sub>I</sub> = GND or V <sub>CC</sub> , OE	V to V <sub>CC</sub> , = don't care			±100			±100	μA	
		$V_{CC} = 3.6 V,$	Outputs high	0.07 0.1 0.07 0.1		0.1					
ICC		$I_{O} = 0,$	Outputs low		3.2	5		3.2	5	mA	
	$V_{I} = V_{CC} \text{ or } GND$ Outputs disabled 0.07 0.1 0.1	0.07	0.1								
∆ICC□		$V_{CC} = 3 V$ to 3.6 V, Or Other inputs at $V_{CC}$ or	ie input at V <sub>CC</sub> – 0.6 V, GND			0.2			0.2	mA	
Ci		V <sub>CC</sub> = 3.3 V,	V <sub>I</sub> = 3.3 V or 0		3.5			3.5		pF	
Cio		V <sub>CC</sub> = 3.3 V,	V <sub>O</sub> = 3.3 V or 0		8			8		pF	

<sup>†</sup> All typical values are at  $V_{CC} = 3.3$  V,  $T_A = 25^{\circ}$ C.

<sup>‡</sup> The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>IN</sub> to GND and then raising it to V<sub>IL</sub> max.

§ The bus-hold circuit can source at least the minimum high sustaining current at V<sub>IH</sub> min. I<sub>BHH</sub> should be measured after raising V<sub>IN</sub> to V<sub>CC</sub> and then lowering it to V<sub>IH</sub> min.

 $\P$  An external driver must source at least  $I_{BHLO}$  to switch this node from low to high.

# An external driver must sink at least IBHHO to switch this node from high to low.

|| Current into an output in the high state when VO > VCC

\* High-impedance state during power up or power down

<sup>□</sup>This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.



# switching characteristics over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ ,

V <sub>CC</sub> = 2.5 V ± 0.2 V	V (unless otherwise n	oted) (see Figure 1)		•			•	
DADAMETED	FROM	то	SN54AL	VTH16245	SN74AL	UNIT		
PARAMETER	(INPUT) (OUTPUT)	MIN	MAX	MIN	MAX			
<sup>t</sup> PLH	A or B	B or A	0.5	3.6	0.5	3.6	ns	
<sup>t</sup> PHL	AUB	BUIA	0.5	3.4	0.5	3.4		
<sup>t</sup> PZH	OE	A or B	1.5	<b>4</b> .9	1.5	4.9		
<sup>t</sup> PZL	UE	AUB	15	4	1	4	ns	
<sup>t</sup> PHZ	OE	A or B	1.5	4.9	1.5	4.9	ns	
<sup>t</sup> PLZ	UE UE	7010	29	4.2	1	4.2	115	

# switching characteristics over recommended operating free-air temperature range, C\_L = 50 pF, V\_{CC} = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ALVTH16245		SN74AL	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
<sup>t</sup> PLH	A or B	B or A	0.5	3.1	0.5	3.1	ns
<sup>t</sup> PHL	AUB	BUIA	0.5	2.9	0.5	2.9	115
<sup>t</sup> PZH	ŌĒ	A or B	1	4.2	1	4.2	-
<sup>t</sup> PZL	ÛE	AOID	1.0	3.5	1	3.5	ns
<sup>t</sup> PHZ	ŌĒ	AorB	1.5	5.3	1.5	5.3	00
<sup>t</sup> PLZ	UE	AUL B	1.5	5	1.5	5	ns
skow							

skew

### tps (pin or transition skew), tps = |tPHL - tPHL|

			V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	UNIT
			TYP	ТҮР	UNIT
t <sub>ps</sub> max			438	118	ps

 $t_{OST} = |t_{p\Phi m} - t_{p\Phi n}|$ , where  $\Phi$  is any edge transition (high to low or low to high) measured between any two outputs (m or n) within any given device (see Note 4)

		V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	UNIT
		TYP	TYP	UNIT
toor	A–B	227	248	20
tost	B–A	223	243	ps

NOTE 4: One output switching,  $T_A = 25^{\circ}C$ 

 $t_{OSHL}/t_{OSLH}$  (common edge skew),  $t_{OSHL} = |t_{PHL}max - t_{PHL}min|$  (output skew for low-to-high transitions), and  $t_{OSLH} = |t_{PLH}max - t_{PLH}min|$  (output skew for high-to-low transitions) (see Note 4)

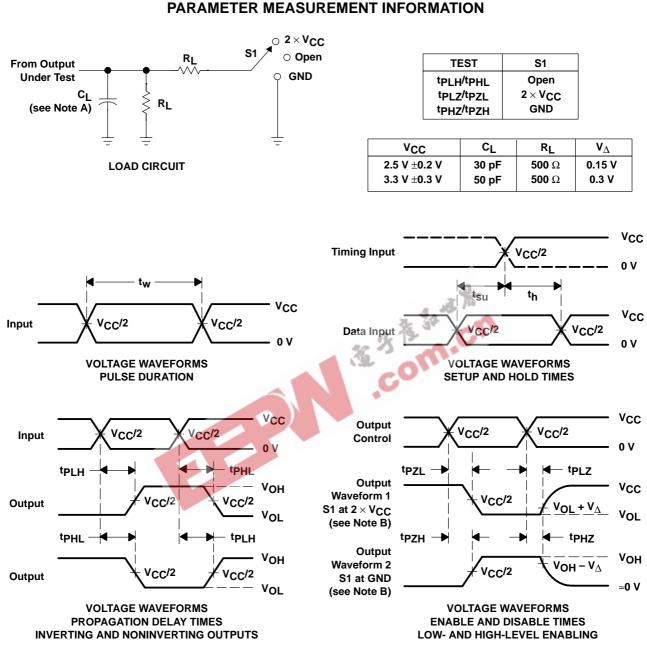
		V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	UNIT
		TYP	TYP	UNIT
tOSLH	A–B	210	145	ps
tOSHL	A-D	243	351	
tOSLH	B-A	207	136	00
toshl	D-A	238	350	ps

NOTE 4: One output switching,  $T_A = 25^{\circ}C$ 

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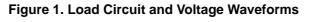


SCES066G - JUNE 1996 - REVISED APRIL 2002



NOTES: A. CL includes probe and jig capacitance.

- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. В. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2 ns, t<sub>f</sub>  $\leq$  2 ns. D. The outputs are measured one at a time with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. tpzL and tpzH are the same as ten.
- G. tPLH and tPHL are the same as tpd.
- All parameters and waveforms are not applicable to all devices. Η.







# PACKAGE OPTION ADDENDUM

6-Dec-2006

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74ALVTH16245DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16245DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16245GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16245VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16245ZQLR	ACTIVE	BGA MI CROSTA R JUNI OR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74ALVTH16245DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16245DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16245GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16245KR	ACTIVE	BGA MI CROSTA R JUNI OR	GQL	56		TBD	SNPB	Level-1-240C-UNLIM
SN74ALVTH16245VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# PACKAGE OPTION ADDENDUM

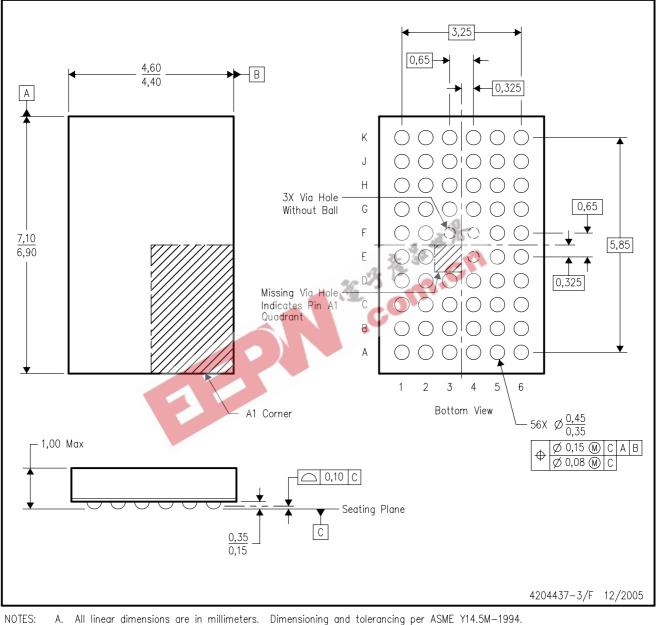
6-Dec-2006

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# ZQL (R-PBGA-N56)

# PLASTIC BALL GRID ARRAY



All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α.

B. This drawing is subject to change without notice.

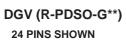
C. Falls within JEDEC MO-225 variation BA.

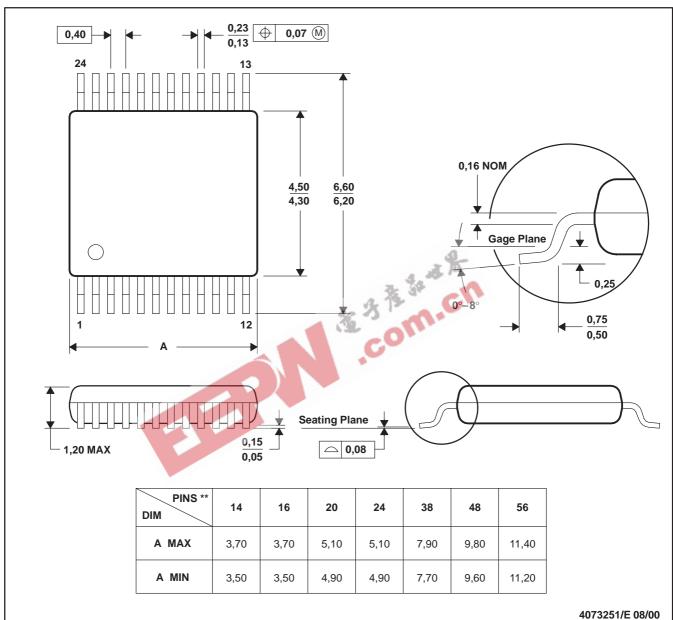
D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

#### PLASTIC SMALL-OUTLINE





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

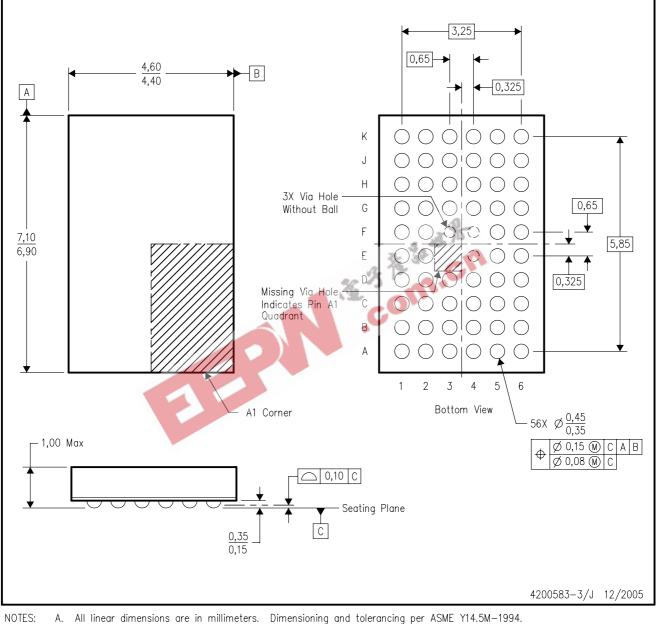
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

- D. Falls within JEDEC: 24/48 Pins MO-153
  - 14/16/20/56 Pins MO-194



# GQL (R-PBGA-N56)

## PLASTIC BALL GRID ARRAY



All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α.

Β. This drawing is subject to change without notice.

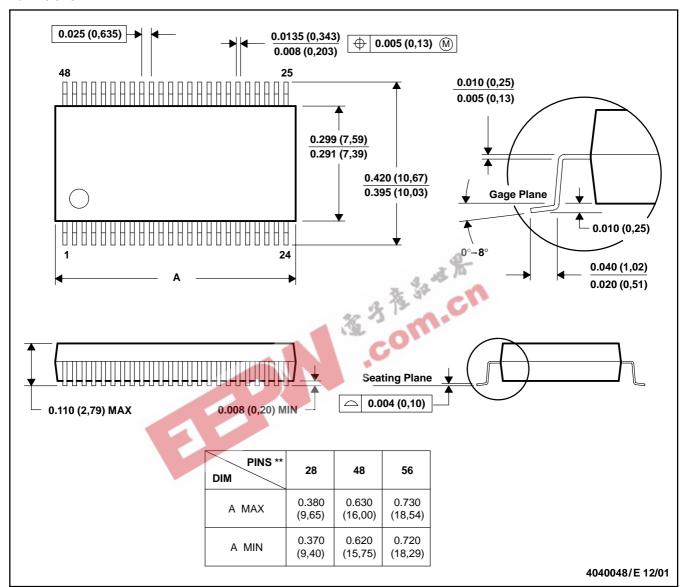
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



MSSO001C - JANUARY 1995 - REVISED DECEMBER 2001

#### PLASTIC SMALL-OUTLINE PACKAGE

DL (R-PDSO-G\*\*) 48 PINS SHOWN



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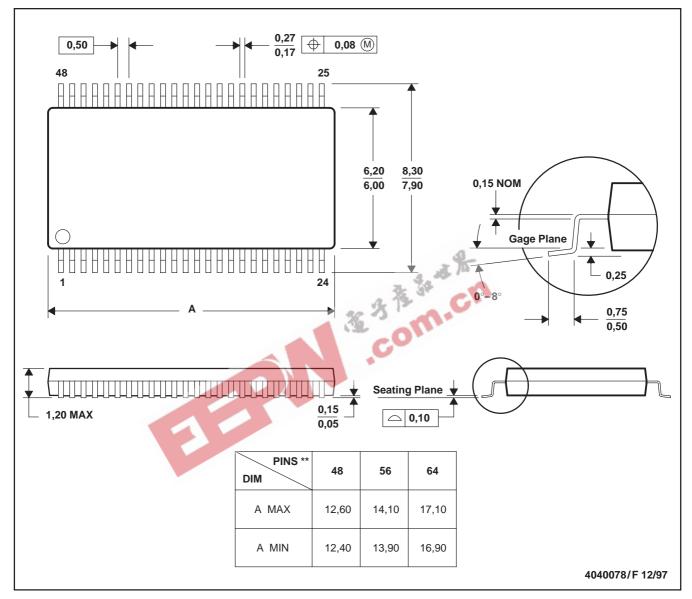
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

#### PLASTIC SMALL-OUTLINE PACKAGE

DGG (R-PDSO-G\*\*) 48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153



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# PACKAGE OPTION ADDENDUM

30-Mar-2007

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
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SN74ALVTH16245KR	NRND	BGA MI CROSTA R JUNI OR	GQL	56	1000	TBD	SNPB	Level-1-240C-UNLIM
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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# PACKAGE OPTION ADDENDUM

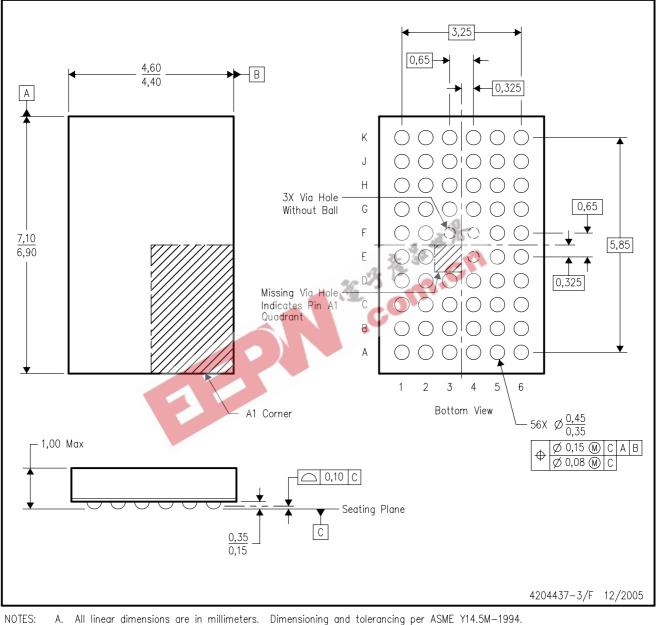
30-Mar-2007

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# ZQL (R-PBGA-N56)

# PLASTIC BALL GRID ARRAY



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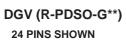
C. Falls within JEDEC MO-225 variation BA.

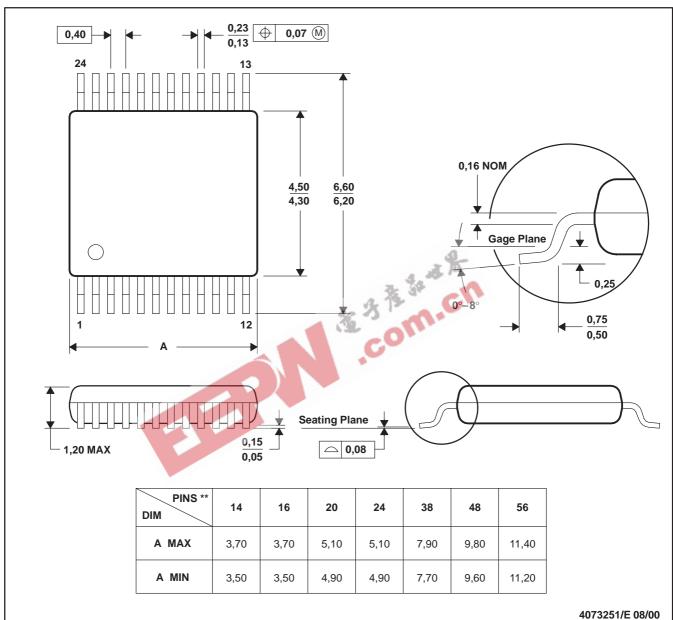
D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

#### PLASTIC SMALL-OUTLINE





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

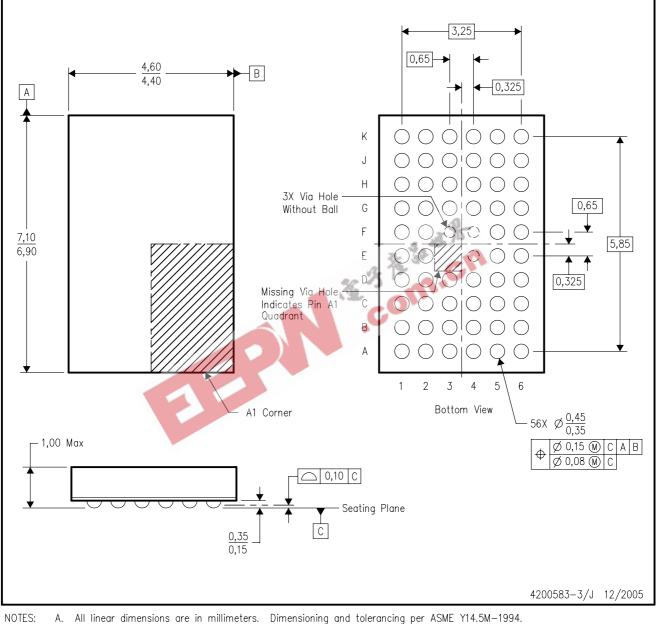
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

- D. Falls within JEDEC: 24/48 Pins MO-153
  - 14/16/20/56 Pins MO-194



# GQL (R-PBGA-N56)

## PLASTIC BALL GRID ARRAY



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Β. This drawing is subject to change without notice.

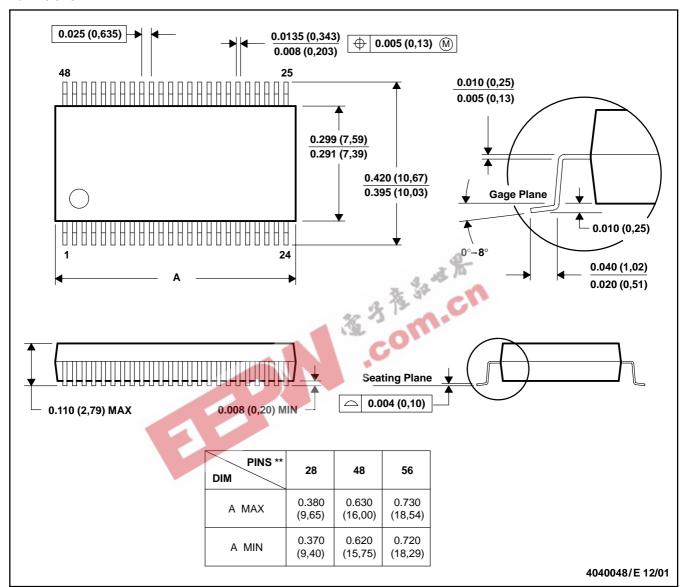
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



MSSO001C - JANUARY 1995 - REVISED DECEMBER 2001

#### PLASTIC SMALL-OUTLINE PACKAGE

DL (R-PDSO-G\*\*) 48 PINS SHOWN



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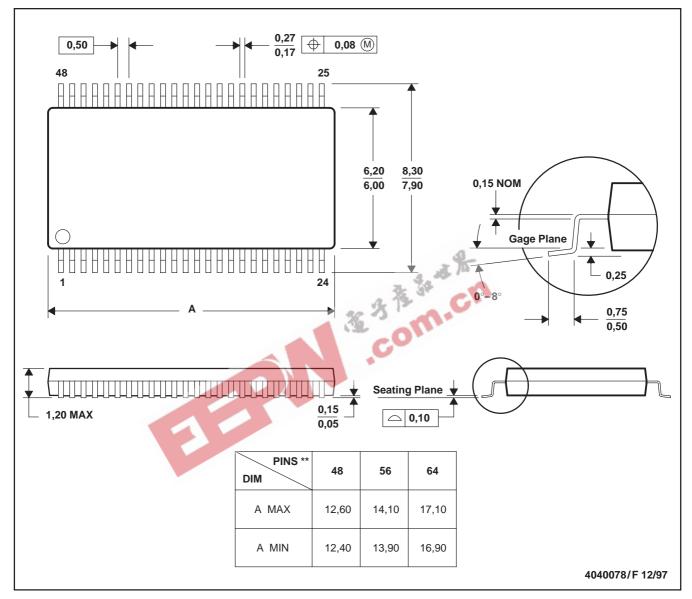
NOTES: A. All linear dimensions are in inches (millimeters).

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- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

#### PLASTIC SMALL-OUTLINE PACKAGE

DGG (R-PDSO-G\*\*) 48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

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C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153



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